



**VN808**

## OCTAL CHANNEL HIGH SIDE DRIVER

PRELIMINARY DATA

| TYPE  | $R_{DS(on)}$   | $I_{OUT}$ | $V_{CC}$ |
|-------|----------------|-----------|----------|
| VN808 | 160 m $\Omega$ | 0.7 A     | 45V      |

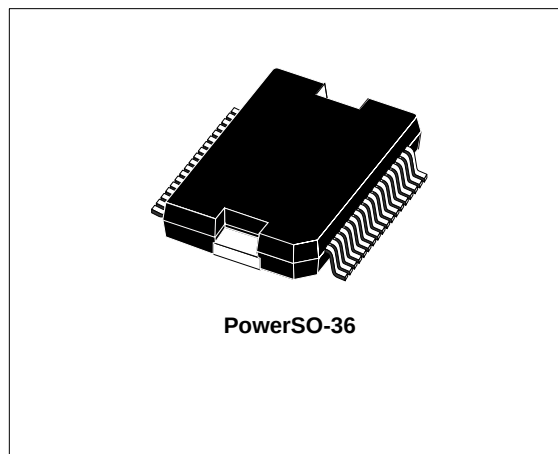
- $V_{CC}/2$  COMPATIBLE INPUT
- JUNCTION OVERTEMPERATURE PROTECTION
- CASE OVERTEMPERATURE PROTECTION FOR THERMAL INDEPENDENCE OF THE CHANNELS
- CURRENT LIMITATION
- SHORTED LOAD PROTECTION
- UNDERVOLTAGE SHUTDOWN
- PROTECTION AGAINST LOSS OF GROUND
- VERY LOW STAND-BY CURRENT
- COMPLIANCE TO 61000-4-4 IEC TEST UP TO 4.4KV (see application schematic page 7)

### DESCRIPTION

The VN808 is a monolithic device designed in STMicroelectronics VIPower M0-3 Technology, intended for driving any kind of load with one side connected to ground.

Active current limitation combined with thermal shutdown and automatic restart, protect the device against overload.

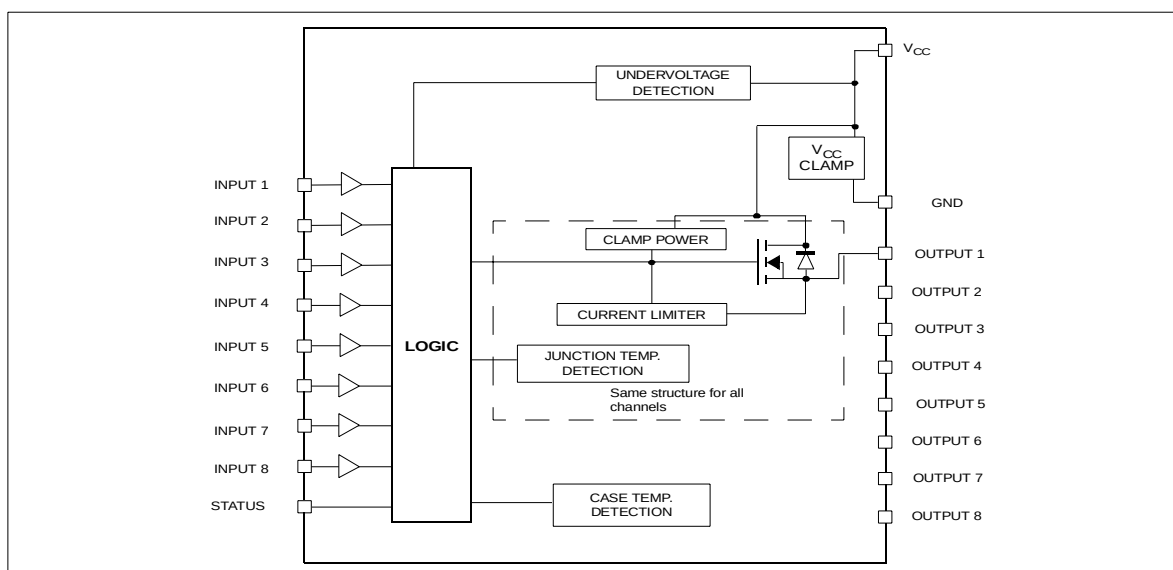
In overload condition, channel turns off and back on automatically so as to maintain junction



temperature between  $T_{TSD}$  and  $T_R$ . If this condition makes case temperature reach  $T_{CSD}$ , overloaded channel is turned off and will restart only when case temperature has decreased down to  $T_{CR}$  (see waveform 3 page 8). Non overloaded channels continue to operate normally.

Device automatically turns off in case of ground pin disconnection. This device is especially suitable for industrial applications conform to IEC 1131 (Programmable Controllers International Standard).

### BLOCK DIAGRAM



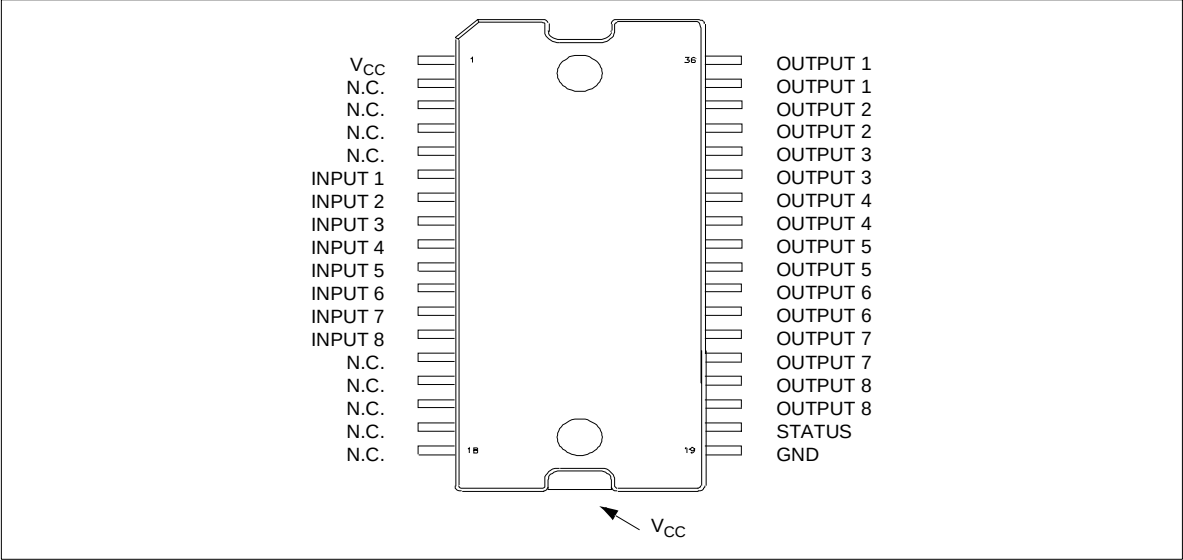
**ABSOLUTE MAXIMUM RATING**

| Symbol     | Parameter                                                                          | Value              | Unit        |
|------------|------------------------------------------------------------------------------------|--------------------|-------------|
| $V_{CC}$   | DC Supply voltage                                                                  | 45                 | V           |
| $-I_{GND}$ | DC Ground pin reverse current                                                      | - 250              | mA          |
|            | TRAN Ground pin reverse current (pulse duration < 1ms)                             | -6                 | A           |
| $I_{OUT}$  | DC Output current                                                                  | Internally Limited | A           |
| $-I_{OUT}$ | Reverse DC output current                                                          | - 2                | A           |
| $I_{IN}$   | DC Input current                                                                   | +/- 10             | mA          |
| $V_{IN}$   | Input voltage range                                                                | -3/+ $V_{CC}$      | V           |
| $V_{ESD}$  | Electrostatic discharge (R=1.5K $\Omega$ ; C=100pF)                                | 2000               | V           |
| $P_{tot}$  | Power dissipation $T_C=25^{\circ}C$                                                | 96                 | W           |
| $L_{max}$  | Max inductive load ( $V_{CC}=24V$ , $R_{LOAD}=48\Omega$ , $T_{amb}=100^{\circ}C$ ) | 2                  | H           |
| $T_j$      | Junction operating temperature                                                     | Internally Limited | $^{\circ}C$ |
| $T_c$      | Case operating temperature                                                         | Internally Limited | $^{\circ}C$ |
| $T_{stg}$  | Storage temperature                                                                | - 55 to 150        | $^{\circ}C$ |

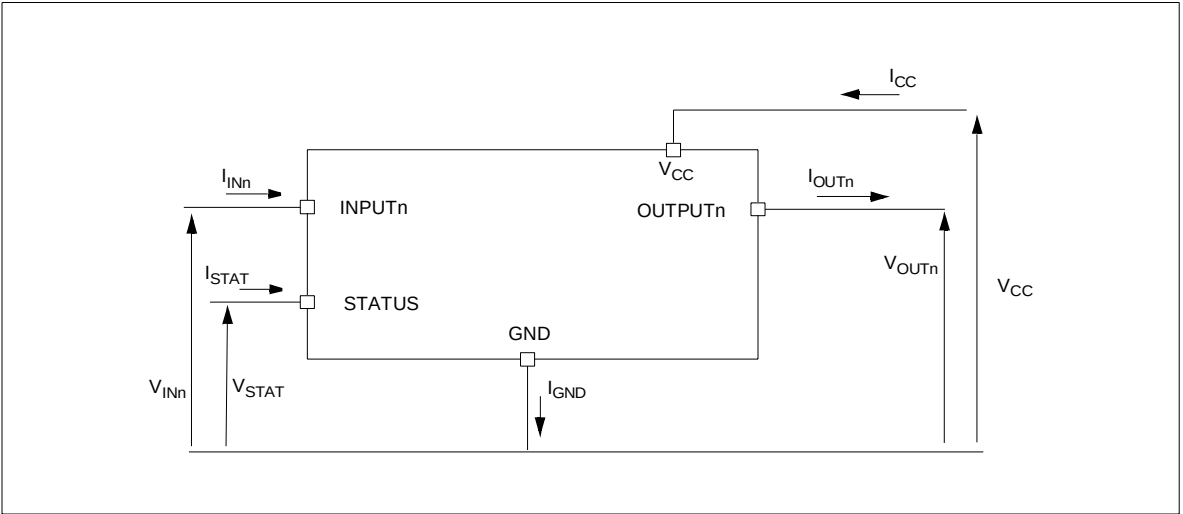
**PIN DEFINITIONS AND FUNCTIONS**

| Pin No         | Symbol   | Function                                          |
|----------------|----------|---------------------------------------------------|
| TAB            | $V_{CC}$ | Positive power supply voltage                     |
| 1              | $V_{CC}$ | Positive power supply voltage                     |
| 2,3,4,5        | NC       | Not connected                                     |
| 6              | INPUT 1  | Input of channel 1                                |
| 7              | INPUT 2  | Input of channel 2                                |
| 8              | INPUT 3  | Input of channel 3                                |
| 9              | INPUT 4  | Input of channel 4                                |
| 10             | INPUT 5  | Input of channel 5                                |
| 11             | INPUT 6  | Input of channel 6                                |
| 12             | INPUT 7  | Input of channel 7                                |
| 13             | INPUT 8  | Input of channel 8                                |
| 14,15,16,17,18 | NC       | Not connected                                     |
| 19             | GND      | Logic ground                                      |
| 20             | STATUS   | Common open source diagnostic for overtemperature |
| 21,22          | OUTPUT 8 | High-Side output of channel 8                     |
| 23,24          | OUTPUT 7 | High-Side output of channel 7                     |
| 25,26          | OUTPUT 6 | High-Side output of channel 6                     |
| 27,28          | OUTPUT 5 | High-Side output of channel 5                     |
| 29,30          | OUTPUT 4 | High-Side output of channel 4                     |
| 31,32          | OUTPUT 3 | High-Side output of channel 3                     |
| 33,34          | OUTPUT 2 | High-Side output of channel 2                     |
| 35,36          | OUTPUT 1 | High-Side output of channel 1                     |

CONNECTION DIAGRAM (TOP VIEW)



CURRENT AND VOLTAGE CONVENTIONS



## THERMAL DATA

| Symbol         | Parameter                               | Value | Unit |
|----------------|-----------------------------------------|-------|------|
| $R_{thj-case}$ | Thermal resistance junction-case        | Max   | 1.3  |
| $R_{thj-amb}$  | Thermal resistance junction-ambient (*) | Max   | 50   |

(\*) When mounted on FR4 printed circuit board with 0.5 cm<sup>2</sup> of copper area (at least 35μ thick) connected to all TAB pins.

**ELECTRICAL CHARACTERISTICS** (10.5V< $V_{CC}$ <32V; -40°C< $T_J$ <125°C, unless otherwise specified)  
**POWER**

| Symbol          | Parameter                                     | Test Conditions                                                                                                           | Min  | Typ | Max        | Unit     |
|-----------------|-----------------------------------------------|---------------------------------------------------------------------------------------------------------------------------|------|-----|------------|----------|
| $V_{CC}$        | Operating supply voltage                      |                                                                                                                           | 10.5 |     | 45         | V        |
| $V_{USD}$       | Undervoltage shut-down                        |                                                                                                                           | 7    |     | 10.5       | V        |
| $R_{ON}$        | On state resistance                           | $I_{OUT}=0.5A$ ; $T_J=25^{\circ}C$<br>$I_{OUT}=0.5A$                                                                      |      |     | 160<br>280 | mΩ<br>mΩ |
| $I_S$           | Supply current                                | Off state; $V_{CC}=24V$ ; $T_{case}=25^{\circ}C$<br>On state (all channels ON); $V_{CC}=24V$ ;<br>$T_{case}=100^{\circ}C$ |      |     | 150<br>12  | μA<br>mA |
| $I_{LGND}$      | Output current at turn-off                    | $V_{CC}=V_{STAT}=V_{IN}=V_{GND}=24V$<br>$V_{OUT}=0V$                                                                      |      |     | 1          | mA       |
| $I_{L(off)}$    | Off state output current                      | $V_{IN}=V_{OUT}=0V$                                                                                                       | 0    |     | 5          | μA       |
| $V_{OUToff}$    | Off state output voltage                      | $V_{IN}=0V$ , $I_{OUT}=0A$                                                                                                |      |     | 3          | V        |
| $t_d(V_{CCon})$ | Power-on delay time from $V_{CC}$ rising edge | (see Fig.1b: switching time waveforms)                                                                                    |      | 1   |            | ms       |

SWITCHING ( $V_{CC}=24V$ )

| Symbol                | Parameter              | Test Conditions                                               | Min | Typ | Max | Unit |
|-----------------------|------------------------|---------------------------------------------------------------|-----|-----|-----|------|
| $t_{on}$              | Turn-on time           | $R_L=48\Omega$ from 80% $V_{OUT}$ (**)                        |     | 50  | 100 | μs   |
| $t_{off}$             | Turn-off time          | $R_L=48\Omega$ to 10% $V_{OUT}$ (**)                          |     | 75  | 150 | μs   |
| $dV_{OUT}/dt_{(on)}$  | Turn-on voltage slope  | $R_L=48\Omega$ from $V_{OUT}=2.4V$ to<br>$V_{OUT}=19.2V$ (**) |     | 0.7 |     | V/μs |
| $dV_{OUT}/dt_{(off)}$ | Turn-off voltage slope | $R_L=48\Omega$ from $V_{OUT}=21.6V$ to<br>$V_{OUT}=2.4V$ (**) |     | 1.5 |     | V/μs |

(\*\*) see figure 1a: switching time waveforms

## INPUT PIN

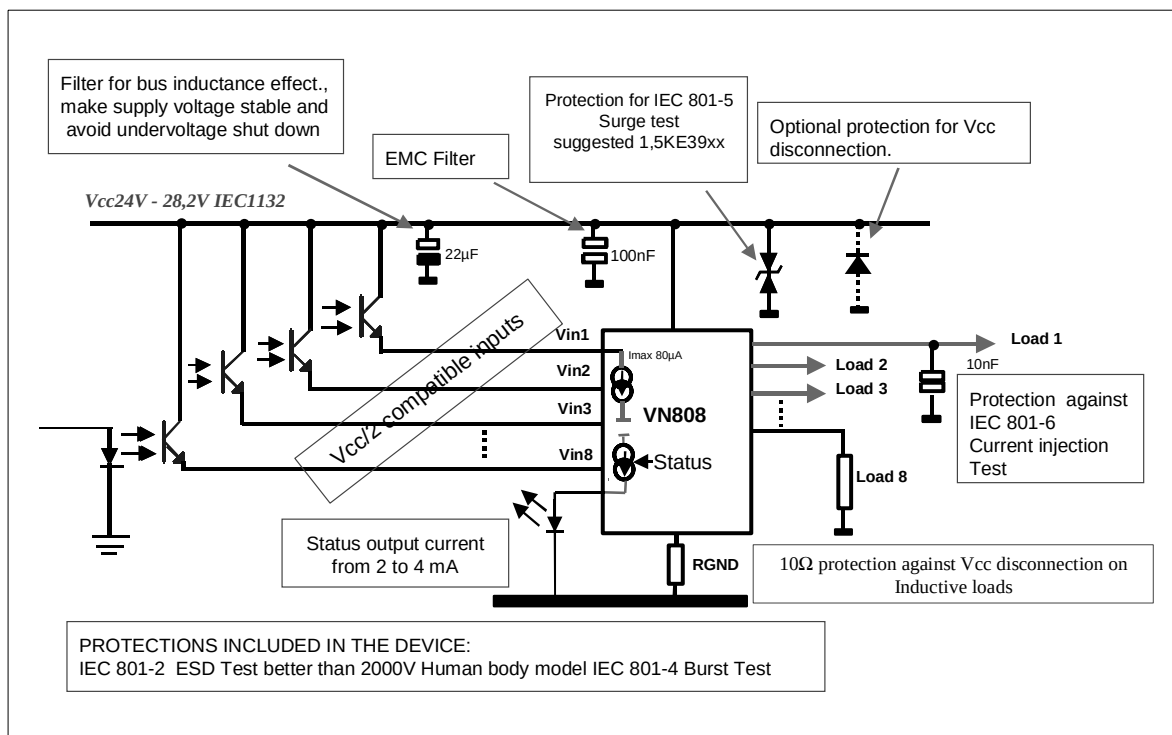
| Symbol        | Parameter                | Test Conditions      | Min          | Typ | Max          | Unit |
|---------------|--------------------------|----------------------|--------------|-----|--------------|------|
| $V_{INL}$     | Input low level          |                      |              |     | $V_{CC/2}-1$ | V    |
| $I_{INL}$     | Low level input current  | $V_{IN}=V_{CC/2}-1V$ | 80           |     |              | μA   |
| $V_{INH}$     | Input high level         |                      | $V_{CC/2}+1$ |     |              | V    |
| $I_{INH}$     | High level input current | $V_{IN}=V_{CC/2}+1V$ |              | 150 | 260          | μA   |
| $V_{I(hyst)}$ | Input hysteresis voltage |                      |              | 0.6 |              | V    |
| $I_{IN}$      | Input current            | $V_{IN}=V_{CC}=32V$  |              |     | 300          | μA   |

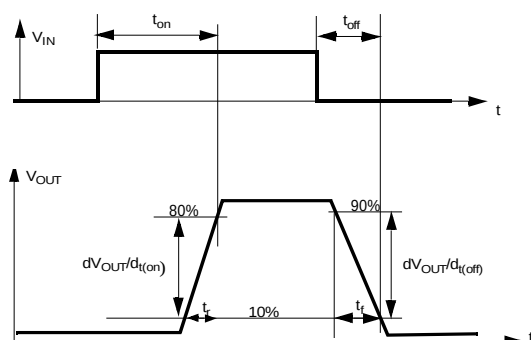
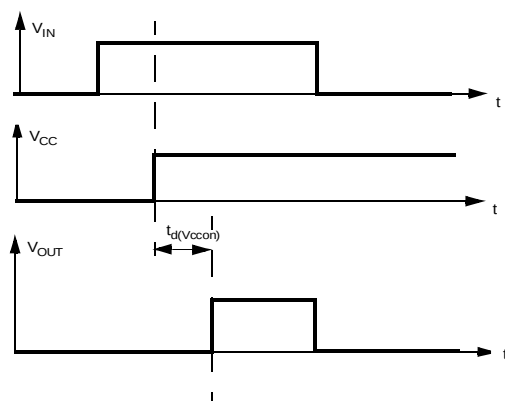
**ELECTRICAL CHARACTERISTICS** (continued)**PROTECTIONS**

| Symbol      | Parameter                      | Test Conditions                     | Min         | Typ         | Max         | Unit |
|-------------|--------------------------------|-------------------------------------|-------------|-------------|-------------|------|
| $T_{CSD}$   | Case shut-down temperature     |                                     | 125         | 130         | 135         | °C   |
| $T_{CR}$    | Case reset temperature         |                                     | 110         |             |             | °C   |
| $T_{CHYST}$ | Case thermal hysteresis        |                                     | 7           | 15          |             | °C   |
| $T_{TSD}$   | Junction shut-down temperature |                                     | 150         | 175         | 200         | °C   |
| $T_R$       | Junction Reset temperature     |                                     | 135         |             |             | °C   |
| $T_{HYST}$  | Junction thermal hysteresis    |                                     | 7           | 15          |             | °C   |
| $I_{lim}$   | DC Short circuit current       | $V_{CC}=24V$ ; $R_{LOAD}=10m\Omega$ | 0.7         |             | 1.7         | A    |
| $V_{demag}$ | Turn-off output clamp voltage  | $I_{OUT}=0.5\text{ A}$ ; $L=6mH$    | $V_{CC}-47$ | $V_{CC}-52$ | $V_{CC}-57$ | V    |

**STATUS PIN**

| Symbol       | Parameter                 | Test Conditions                                              | Min | Typ         | Max | Unit    |
|--------------|---------------------------|--------------------------------------------------------------|-----|-------------|-----|---------|
| $I_{HSTAT}$  | High level output current | $V_{CC}=18...32V$ , $R_{STAT}=1k\Omega$<br>(Fault condition) | 2   | 3           | 4   | mA      |
| $I_{LSTAT}$  | Leakage current           | Normal operation; $V_{CC}=32V$                               |     |             | 0.1 | $\mu A$ |
| $V_{CLSTAT}$ | Clamp voltage             | $I_{STAT}=1mA$<br>$I_{STAT}=-1mA$                            | 6.0 | 6.8<br>-0.7 | 8.0 | V<br>V  |

**APPLICATION EXAMPLE**

**Figure 1:** Switching Time Waveforms**Fig. 1a: Turn-on & Turn-off****Fig. 1b:  $V_{CC}$  turn-on**

TRUTH TABLE

| CONDITIONS                                                           | INPUTn | OUTPUTn | STATUS |
|----------------------------------------------------------------------|--------|---------|--------|
| Normal operation                                                     | L      | L       | L      |
|                                                                      | H      | H       | L      |
| Current limitation                                                   | L      | L       | L      |
|                                                                      | H      | X       | L      |
| Overtemperature (see waveforms 3,4 page 9,10)<br>--> $T_j > T_{TSD}$ | L      | L       | L      |
|                                                                      | H      | L       | H      |
| Undervoltage                                                         | L      | L       | X      |
|                                                                      | H      | L       | X      |

APPLICATION SCHEMATIC

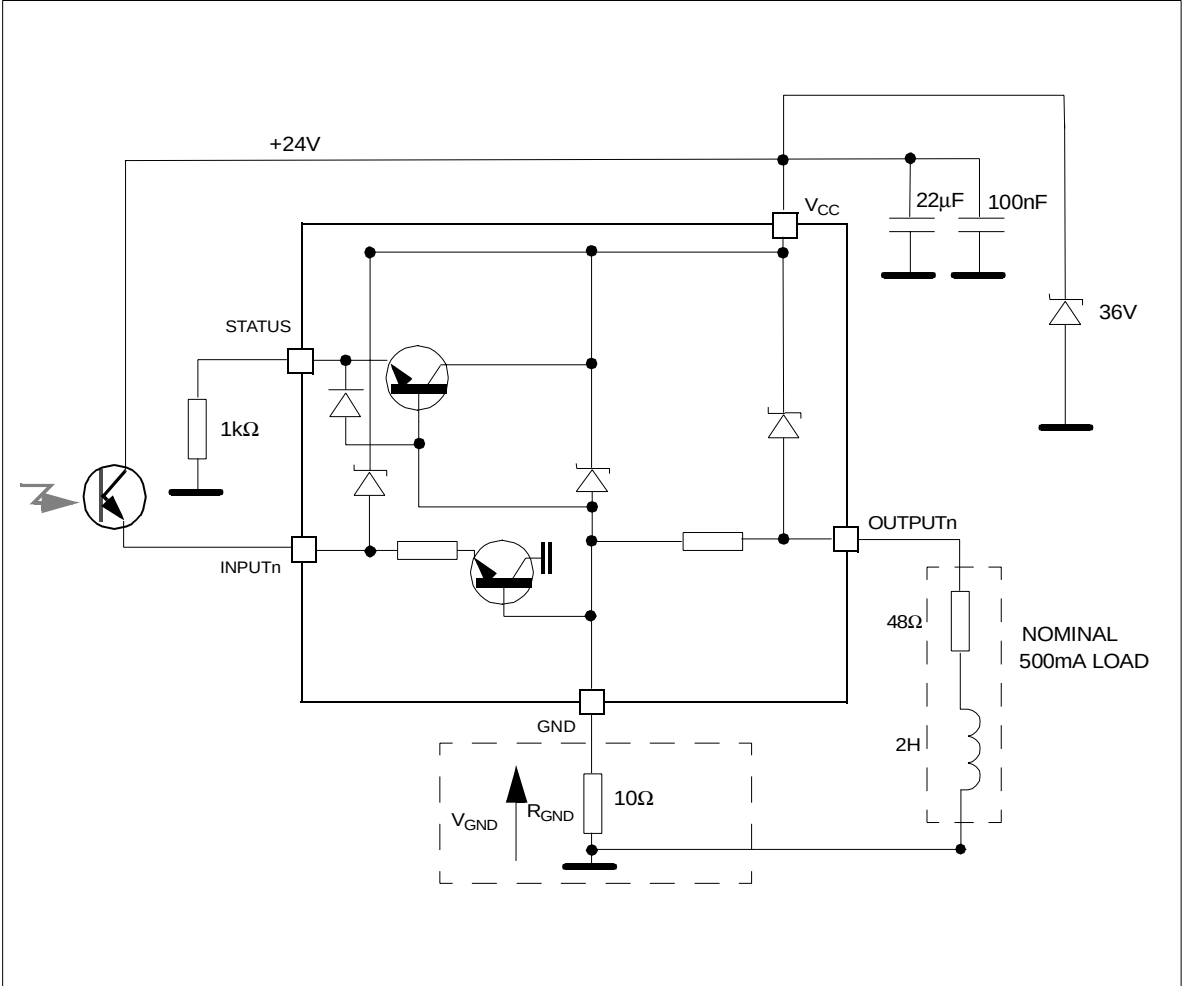
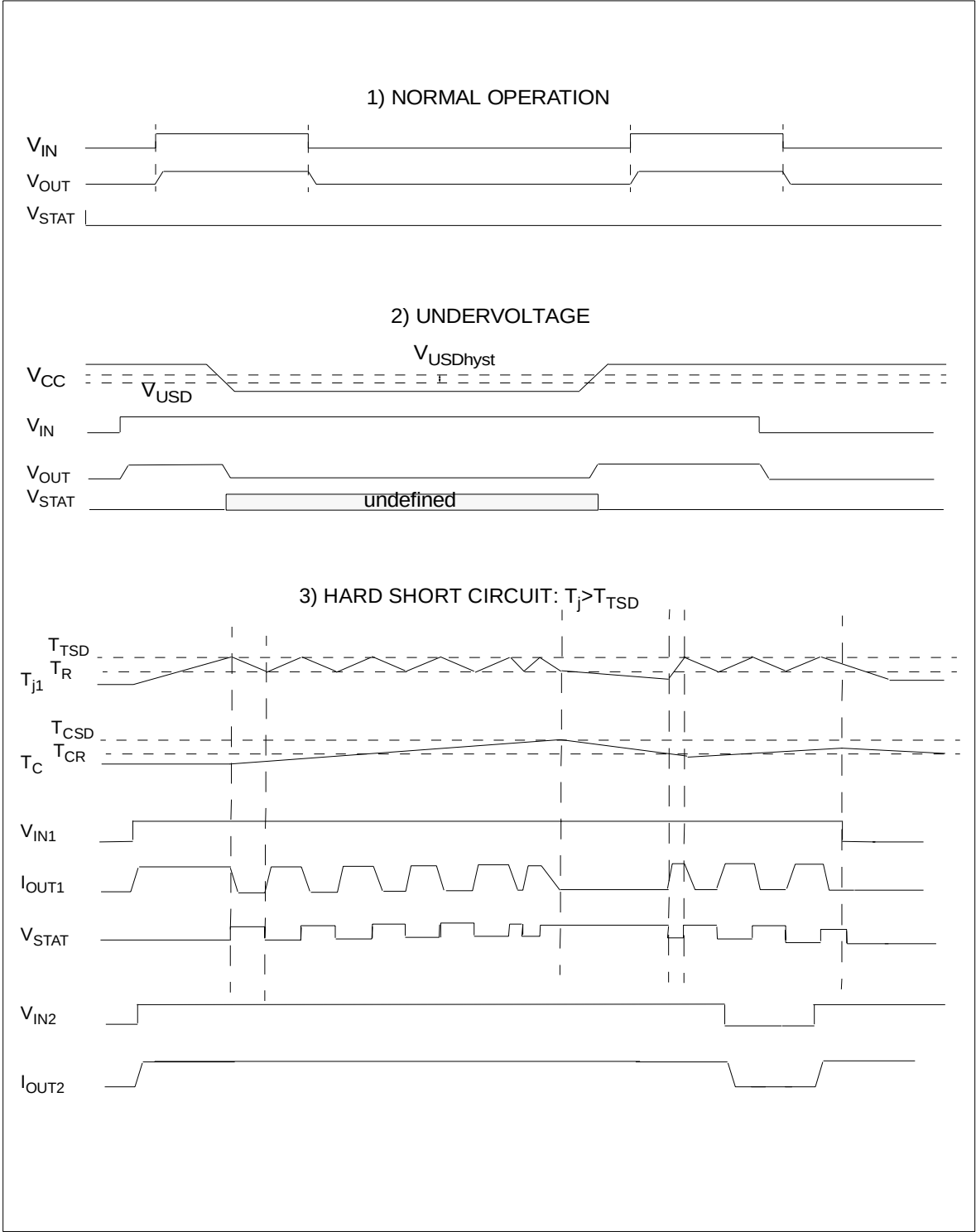
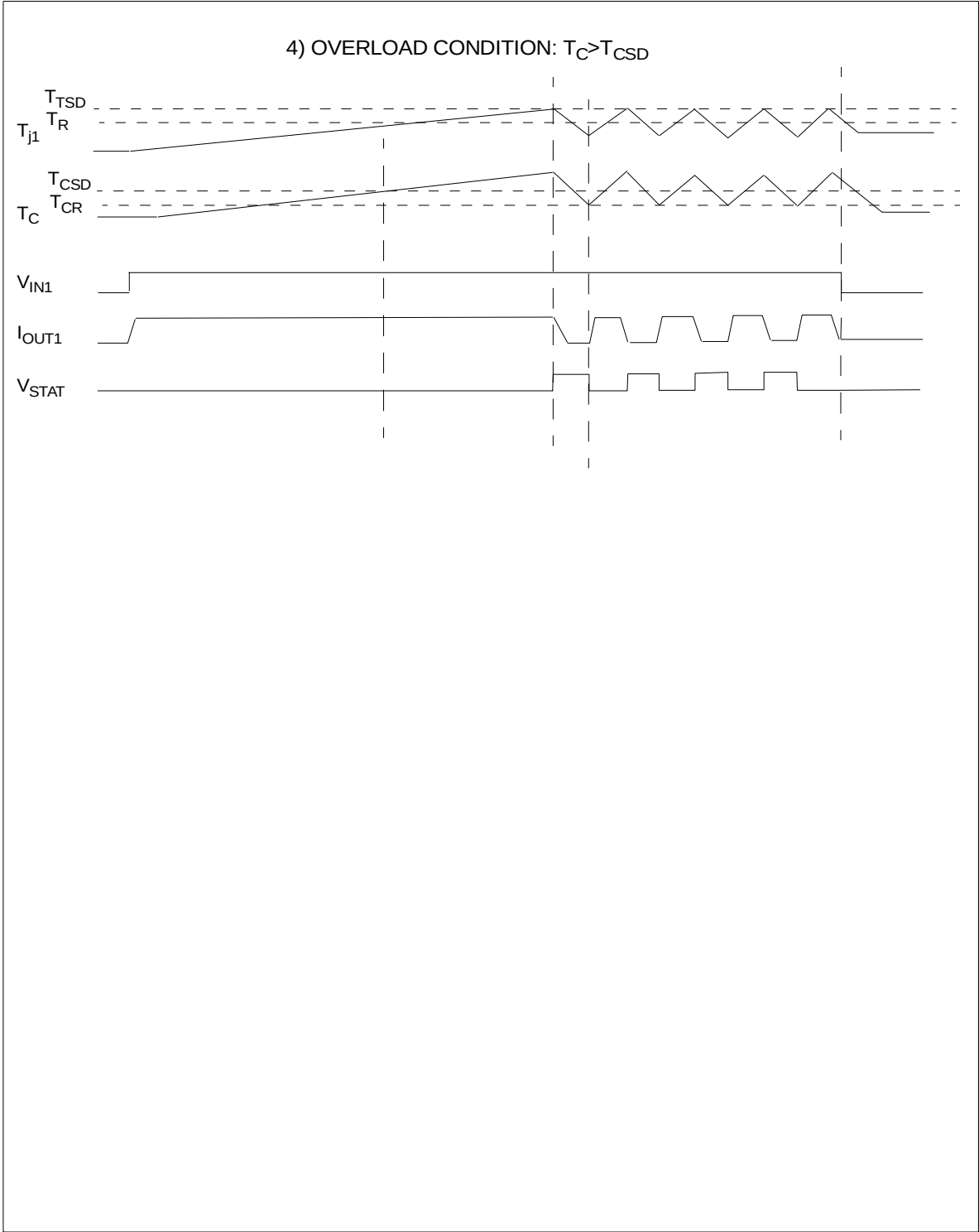


Figure 2: Waveforms





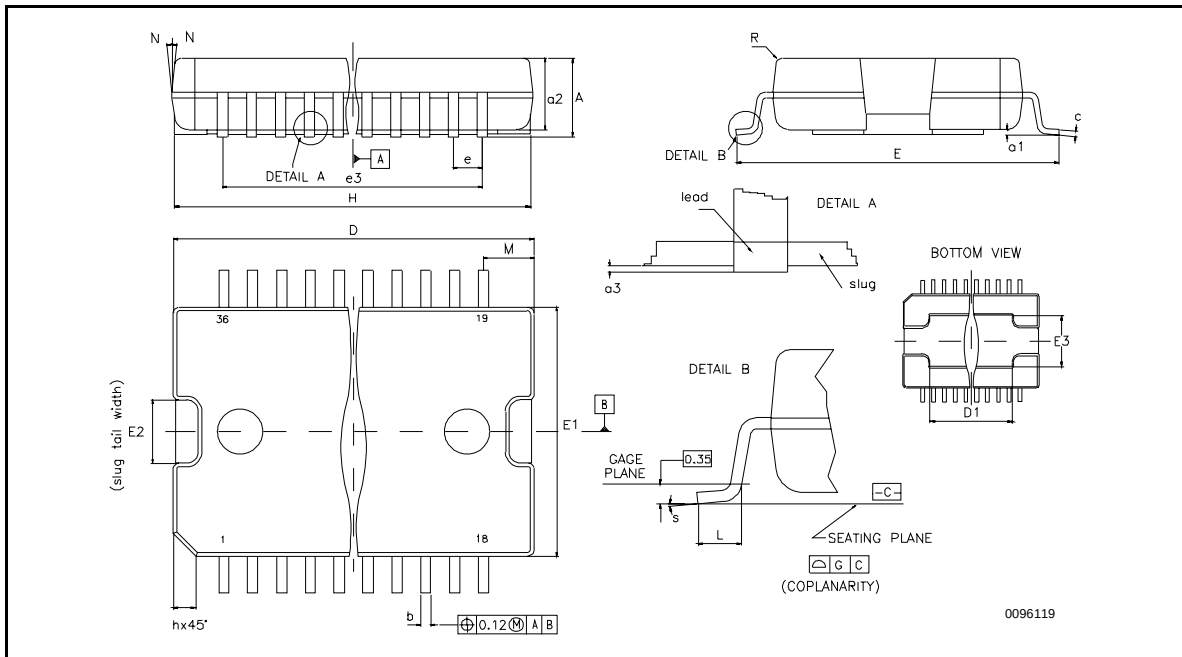
Waveforms (continued)



### PowerSO-36 MECHANICAL DATA

| DIM.   | mm.       |       |       | inch  |        |       |
|--------|-----------|-------|-------|-------|--------|-------|
|        | MIN.      | TYP   | MAX.  | MIN.  | TYP.   | MAX.  |
| A      |           |       | 3.60  |       |        | 0.141 |
| a1     | 0.10      |       | 0.30  | 0.004 |        | 0.012 |
| a2     |           |       | 3.30  |       |        | 0.130 |
| a3     | 0         |       | 0.10  | 0     |        | 0.004 |
| b      | 0.22      |       | 0.38  | 0.008 |        | 0.015 |
| c      | 0.23      |       | 0.32  | 0.009 |        | 0.012 |
| D (1)  | 15.80     |       | 16.00 | 0.622 |        | 0.630 |
| D1     | 9.40      |       | 9.80  | 0.370 |        | 0.385 |
| E      | 13.90     |       | 14.50 | 0.547 |        | 0.570 |
| E1 (1) | 10.90     |       | 11.10 | 0.429 |        | 0.437 |
| E2     |           |       | 2.90  |       |        | 0.114 |
| E3     | 5.80      |       | 6.20  | 0.228 |        | 0.244 |
| e      |           | 0.65  |       |       | 0.0256 |       |
| e3     |           | 11.05 |       |       | 0.435  |       |
| G      | 0         |       | 0.10  | 0     |        | 0.004 |
| H      | 15.50     |       | 15.90 | 0.610 |        | 0.626 |
| h      |           |       | 1.10  |       |        | 0.043 |
| L      | 0.80      |       | 1.10  | 0.031 |        | 0.043 |
| N      | 10° (max) |       |       |       |        |       |
| S      | 8° (max)  |       |       |       |        |       |

- (1): "D" and "E1" do not include mold flash or protrusions  
 - Mold flash or protrusions shall not exceed 0.15mm (0.006 inch)  
 - Critical dimensions are "a3", "E" and "G".



Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a trademark of STMicroelectronics

© 2003 STMicroelectronics - Printed in ITALY- All Rights Reserved.

STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia -  
Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - U.S.A.

<http://www.st.com>

